

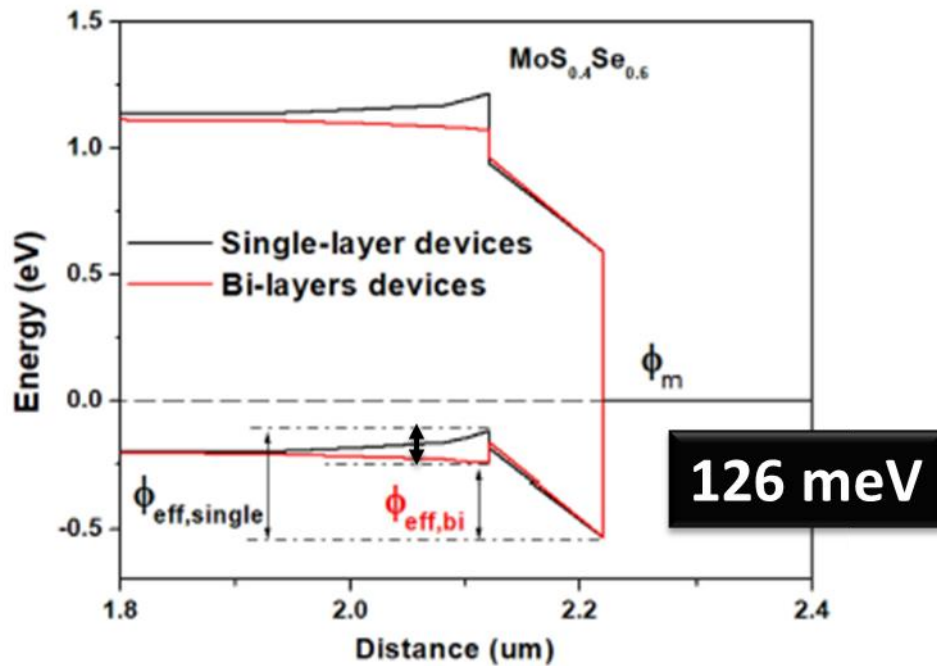
## Enhancement of the bifacial absorber of Silver Antimony Sulfur Selenide photovoltaic devices

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The comparison of the and diagram for Back Contact Schottky Barriers for the bifacial and single layer devices.



- The comparison of the and diagram for Back Contact Schottky Barriers shows the effective back contact Schottky hole barrier of single-layer devices is greater by 126 meV than bilayer devices.